

# Search for new GeV resonances in the dimuon mass spectrum

- Several theoretical arguments and some experimental results require an extension of the Standard Model (SM)
- In particular, the SM cannot explain the nature of the Dark Matter (DM)
- At present, the most popular hypothesis on the DM is that it is composed of **weakly interacting massive particle** (WIMPs)
- However the existence of massive WIMPs is strictly constrained by the recent LHC results
- On the other hand, in the last years the idea that DM could be light started to gain popularity (because of DAMA and CoGeNT results...)
  - In particular, the idea of light DM interacting with new  $O(1)$  GeV gauge bosons has been widely investigated<sup>1</sup>

<sup>1</sup> J.Phys.G30:279-286,2004

JHEP 1109:128,2011

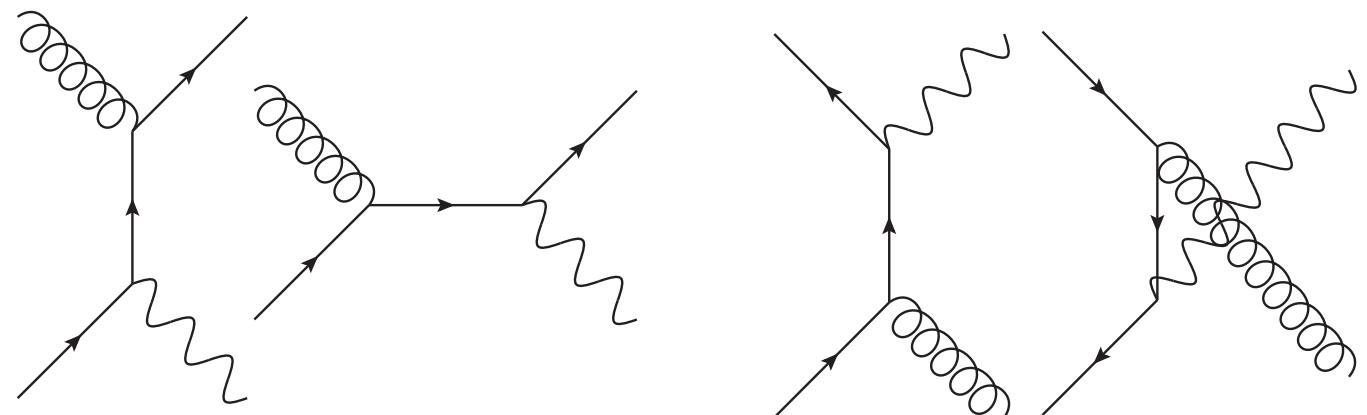
JCAP 1008:018,2010

# Search for new GeV resonances in the dimuon mass spectrum

- In addition to this new light (scalar) resonances are also expected in other scenarios like Two-Higgs-Doublet Models<sup>2</sup>, etc... <sup>2</sup> [arXiv:1412.3385](#)
- Although both high-mass and low-mass ( $< 1$  GeV) new resonances are highly constrained, limits on new IMR resonances are looser<sup>3</sup> <sup>3</sup> [JHEP 0907:051,2009](#)
- The use of p-p collisions to look for new  $O(1)$  GeV gauge bosons could be disfavored w.r.t Pb-Pb collisions [Phys.Rev.C81:034911,2010](#)
- For Pb-Pb collisions the QGP provides an additional thermal source of dileptons (much larger than that from non-thermal prompt production)

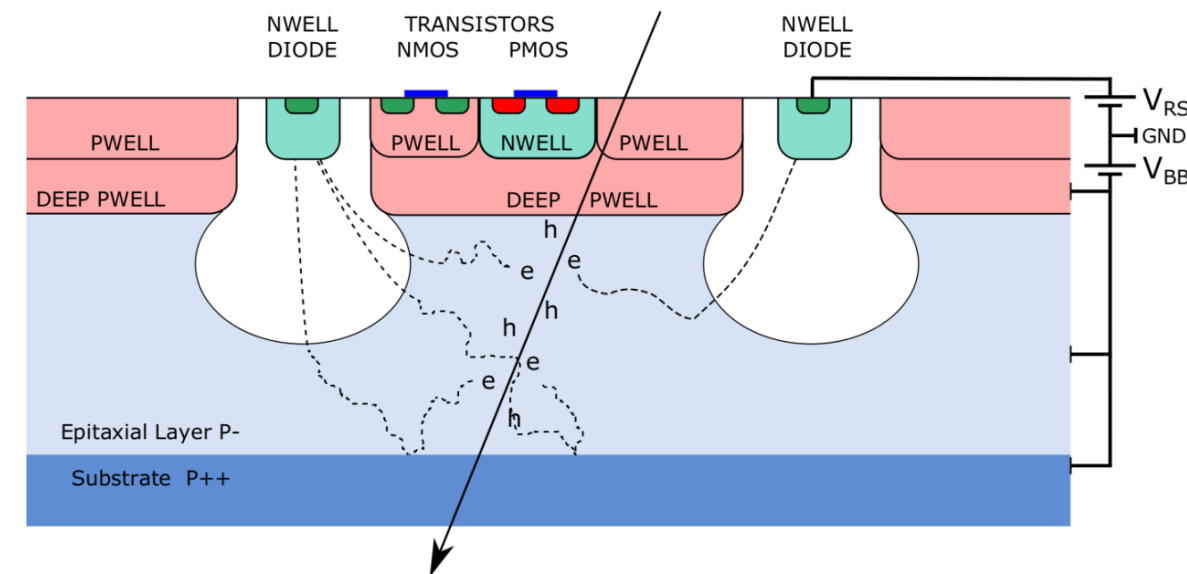
[J.Phys. G38, 025105 \(2011\)](#)

[Phys.Rev. D54, 2399 \(1996\)](#)



- For these reasons a search for new  $O(1)$  gauge bosons decaying to muon pairs has been performed
- The strategy is to perform a **shape analysis** of the invariant mass distribution of opposite-sign muon pairs, in the mass range  $[1.5, 8.0]$   $\text{GeV}/c^2$
- Pb-Pb data at 5 TeV, collected in 2015, have been used
- Combinatorial background is estimated using the mixing technique and is subtracted from data
- The search is performed in different bins of centrality and dimuon  $p_T$

- **ALPIDE** chip is a CMOS Monolithic Active Pixel Sensor developed for the major upgrade of the Inner Tracking System (ITS) of ALICE
- It is implemented in a 180 nm CMOS Imaging Process
- chip size: 15 mm x 30 mm containing a matrix of 512 x 1024 pixels
- pixel size: 29.24  $\mu\text{m}$  x 26.88  $\mu\text{m}$



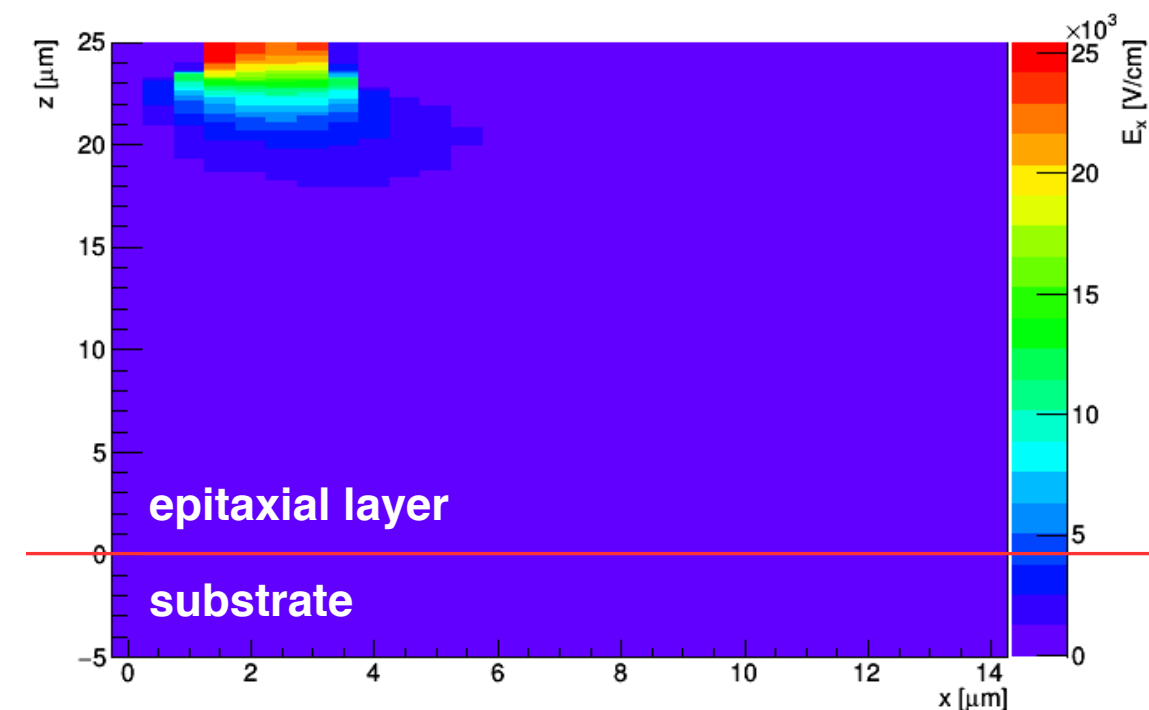
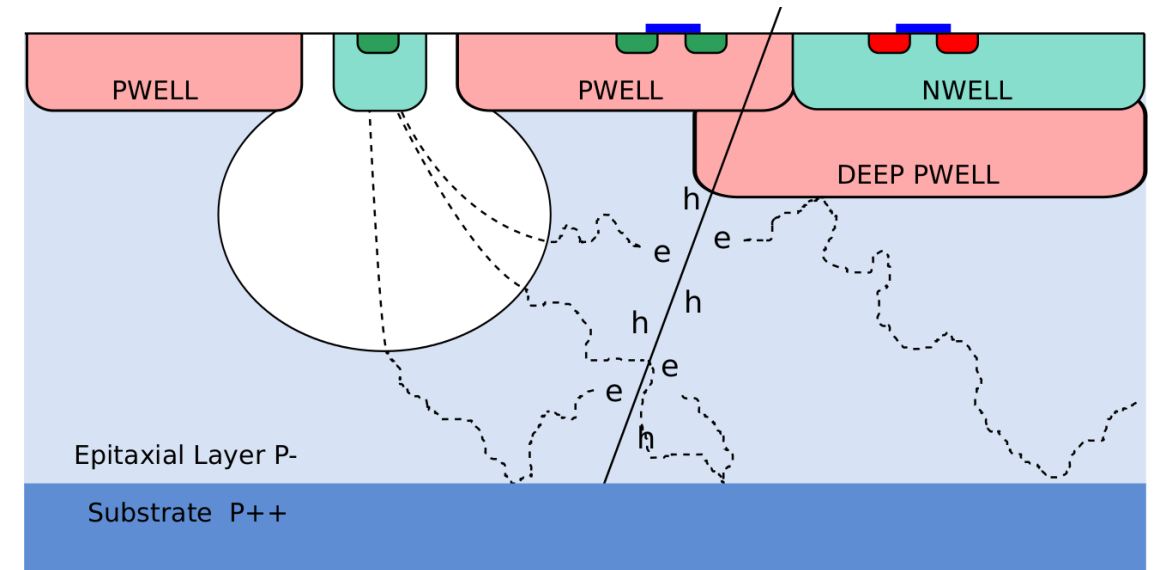
- A charged particle crossing the sensor liberates free charge carriers in the material by ionization
- The electrons released in the epitaxial layer diffuse laterally while remain vertically confined by potential barriers
- The signal sensing elements are n-well diodes ( $\sim 2 \mu\text{m}$  diameter)

- For the simulation of the ALPIDE chip, a **first** approach was to develop a fully parametrized simulation (mainly because of the unknown analog response of the chip)
- In this context, two contributions were considered:
  - A contribution from physics to take into account the dependancy of average cluster size (**ACS**) on the energy deposited in the chip (ACS as a function of  $\beta\gamma$  was parametrised as below)

$$A \cdot \frac{1 + x^2}{x^2} \left[ \frac{1}{2} \cdot \ln(B \cdot x^2) - \frac{x^2}{1 + x^2} - C \cdot \ln(x) \right] \cdot \frac{1}{\cos \theta}$$

- A detector contribution to take into account the dependency of the ACS on detector-based parameters like the particle crossing position, the threshold,  $V_{bb}$ , etc...

- On May, Miljenko Šuljić and Jacobus W. van Hoorne presented a new “microscopic” simulations of MAPS
- Carrier transportation in MAPS sensitive volume is due to both diffusion and drift
- The diffusion was simulated as a random walk of each individual electron
- The drift was simulated using the electric field maps extracted from a TCAD simulation
- Simulation step is the sum of the diffusion and drift steps

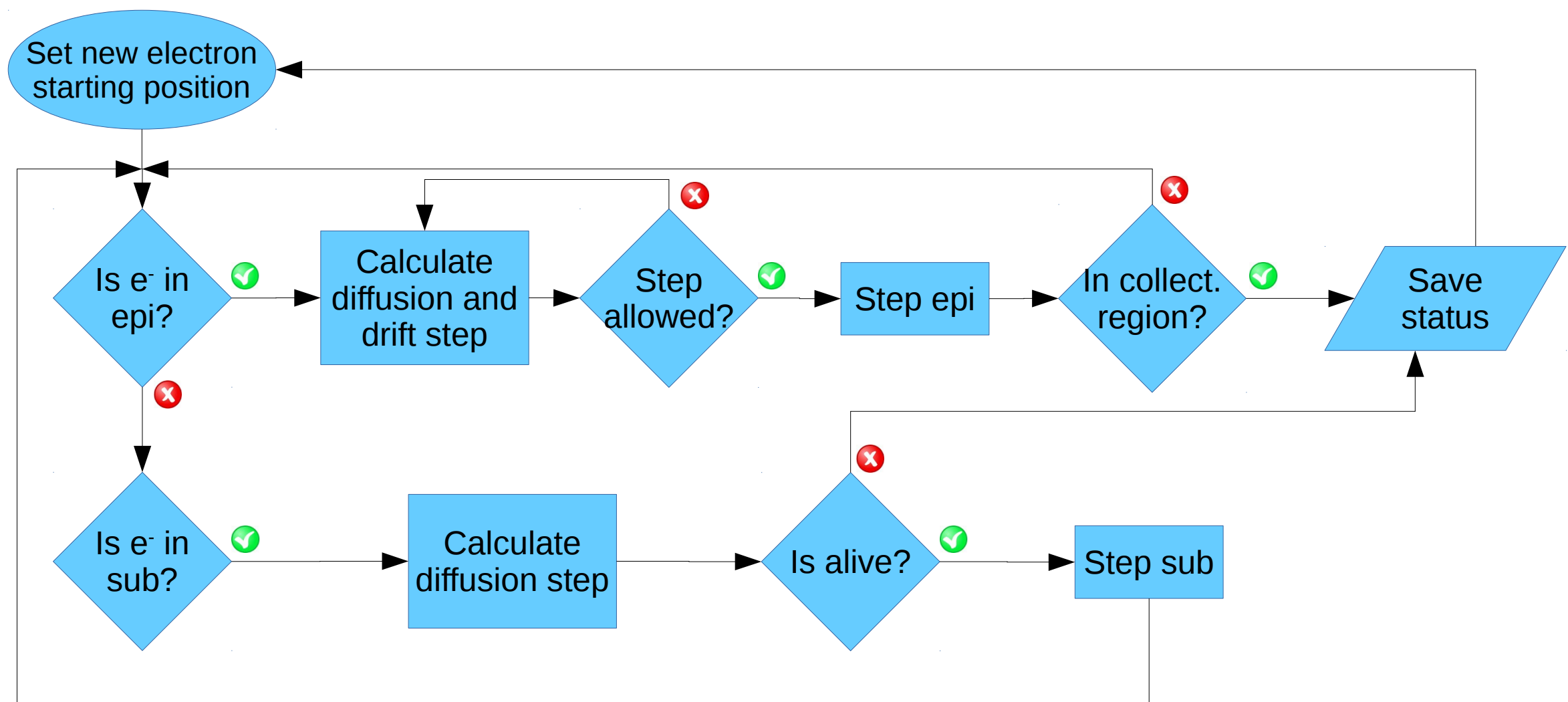




- Collection region is defined by n-well volume + 1/2 spacing and 2  $\mu\text{m}$  thick “high field” region directly below

**Miljenko Šuljić**

## Algorithm

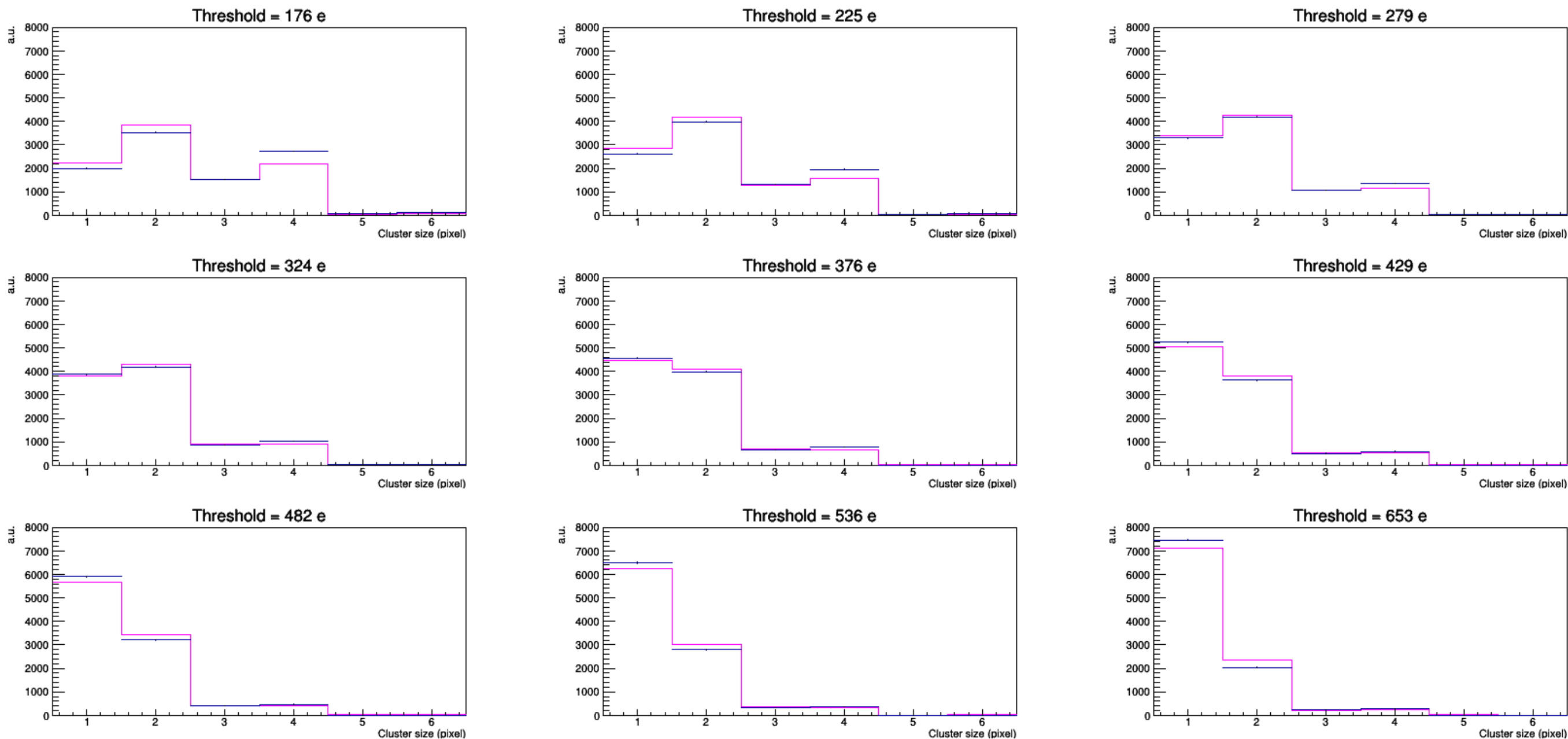


- Total simulated volume: 5x5 pixels

- The agreement between simulation and data is really amazing

**Miljenko Šuljić**

## Cluster size at different thresholds (scaled)

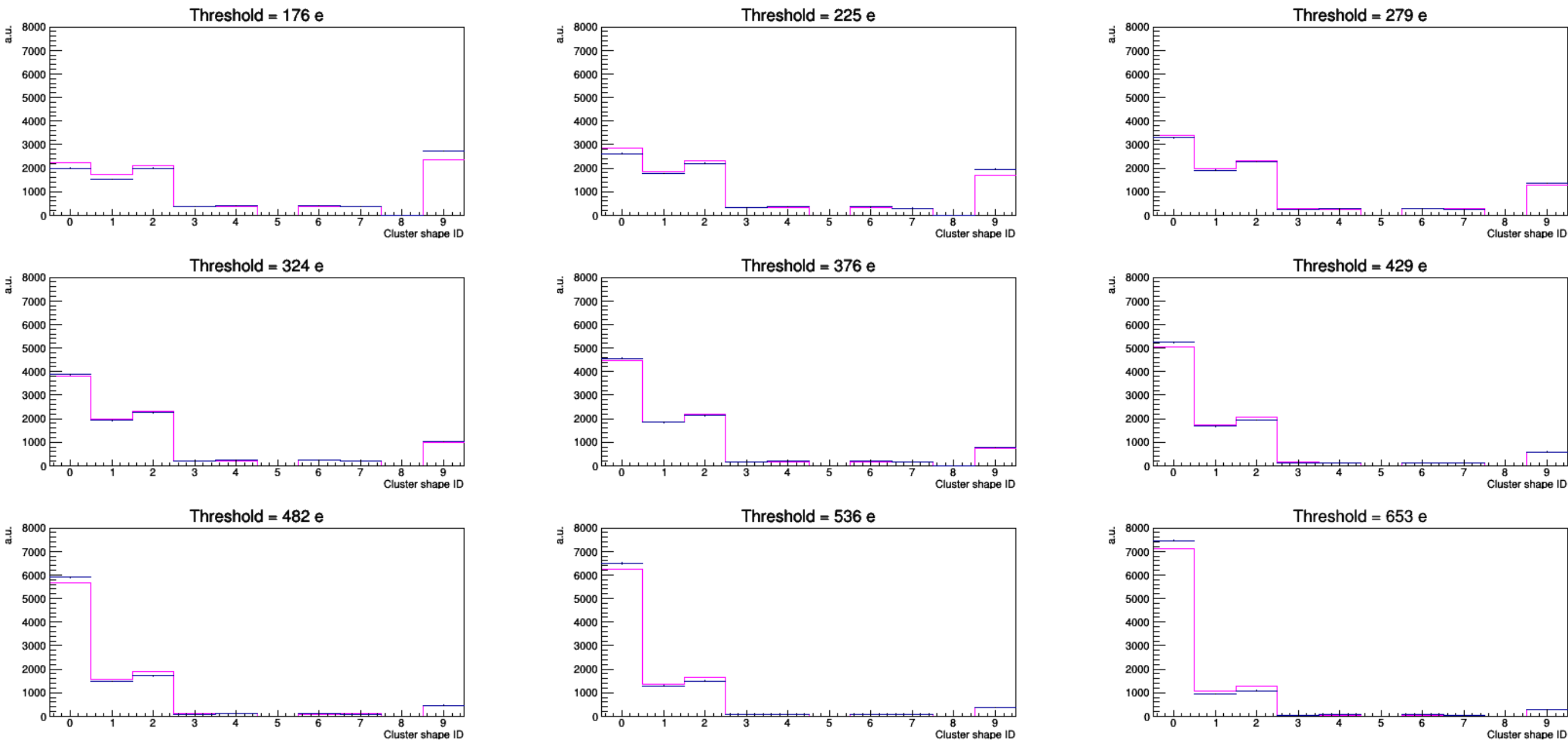




- The agreement between simulation and data is really amazing

**Miljenko Šuljić**

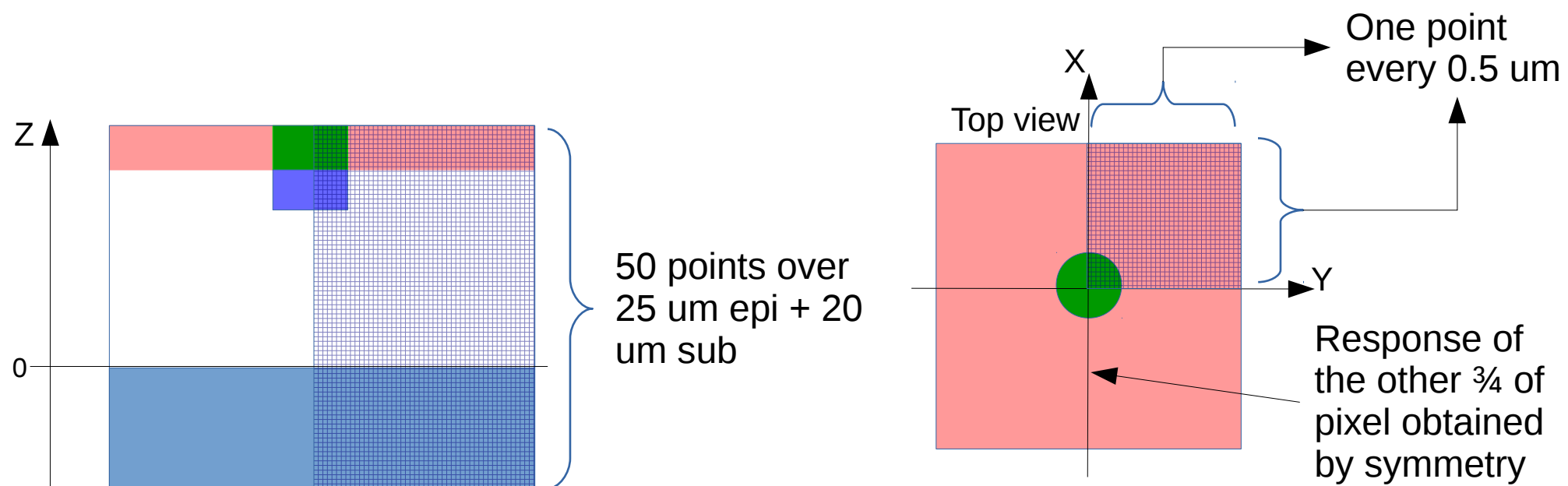
# Cluster shape ID at different thresholds (scaled)



- Because of these impressive results we all decided to stop the development of the parametrized simulation and to port the new microscopic simulation to O2
- Miko's simulation could not be ported to O2 as "it is"
- We decided instead to use the simulation to produce a detector response table to be loaded and used in O2

**Miljenko Šuljić**

## Summable digits - grid



- When we have a hit in a pixel, we divide the path of the crossing particle in the epitaxial layer into  $N_{\text{step}}$  steps
- The energy loss of the track in the chip is converted to  $N_{\text{ele}}$
- For each step  $N_{\text{ele}}/N_{\text{step}}$  electrons are assumed to be generated at the step position (pixel reference frame)
- Using the simulation grid from Miko the (normalised) response matrix is obtained
- The  $N_{\text{step}}$  response matrices from each step are summed up and multiplied by  $N_{\text{ele}}/N_{\text{step}}$  which gives the distribution of the  $N_{\text{ele}}$  electrons in the 5x5 pixels centred around the crossing position

